# 74LVC1G80-Q100

# Single D-type flip-flop; positive-edge trigger

Rev. 3 — 31 January 2022 Product data sheet

## 1. General description

The 74LVC1G80-Q100 is a single positive-edge triggered D-type flip-flop. Data at the D-input that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition will be stored in the flip-flop and its complement will appear at the  $\overline{\mathbb{Q}}$  output. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- · CMOS low power dissipation
- Direct interface with TTL levels
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

# 3. Ordering information

**Table 1. Ordering information** 

Table 1. Ordering information						
Type number	Package					
	Temperature range	Name	Description	Version		
74LVC1G80GW-Q100	-40 °C to +125 °C		plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1		
74LVC1G80GV-Q100	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753		



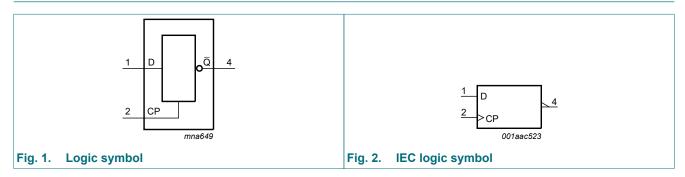
# 4. Marking

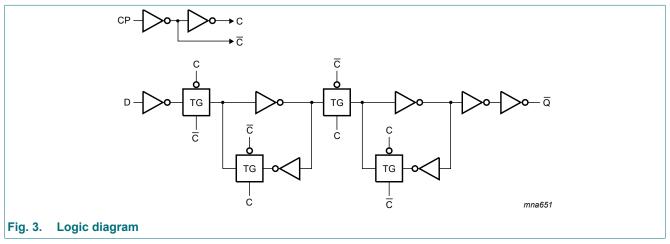
#### Table 2. Marking codes

Type number	Marking[1]
74LVC1G80GW-Q100	VT
74LVC1G80GV-Q100	V80

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

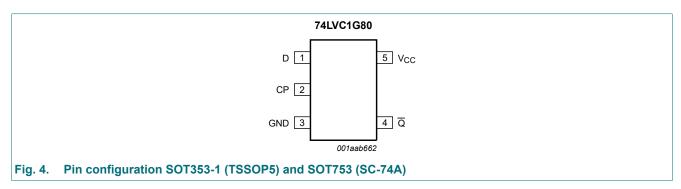
# 5. Functional diagram





# 6. Pinning information

### 6.1. Pinning



# 6.2. Pin description

### Table 3. Pin description

Symbol	Pin	Description
D	1	data input
СР	2	clock pulse input
GND	3	ground (0 V)
Q	4	data output
V <sub>CC</sub>	5	supply voltage

# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ \uparrow = LOW-to-HIGH \ CP \ transition; \ X = don't \ care;$ 

 $\overline{q}$  = lower case letter indicates the state of referenced input, one set-up time prior to the LOW-to-HIGH CP transition.

		Output
СР	D	Q
<b>↑</b>	L	Н
<b>↑</b>	Н	L
L	X	q

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> > V <sub>CC</sub> or V <sub>O</sub> < 0 V		-	±50	mA
Vo	output voltage	Active mode	[1]	-0.5	V <sub>CC</sub> + 0.5	V
		Power-down mode; V <sub>CC</sub> = 0 V	[1]	-0.5	+6.5	V
I <sub>O</sub>	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I <sub>CC</sub>	supply current			-	100	mA
I <sub>GND</sub>	ground current			-100	-	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	250	mW
T <sub>stg</sub>	storage temperature			-65	+150	°C

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	-	5.5	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	-	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	-	-	10	ns/V

<sup>[2]</sup> For SOT353-1 (TSSOP5) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C. For SOT753 (SC-74A) package: P<sub>tot</sub> derates linearly with 3.8 mW/K above 85 °C.

# 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C	·				
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7 × V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	V V - 0.35 × V <sub>CC</sub> V - 0.7 V - 0.8 V - 0.3 × V <sub>CC</sub> V V V V V V V V V V V O.45 V - 0.45 V - 0.45 V - 0.55 V - 0.55 V - 0.55 V	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3 × V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -100 $\mu$ A; $V_{CC}$ = 1.65 V to 5.5 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V	1.2	-	-	V
		I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V	2.2	-	-	V
		I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V	2.3	-	-	V
		I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V	3.8	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V	-	-	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V	-	-	V V V - 0.35 × V <sub>CC</sub> V - 0.7 V - 0.8 V - 0.3 × V <sub>CC</sub> V - O.45 V - O.35 V - O.45 V - O.55 V - O.55 V - O.55 V - O.55 V - O.1 ±1 µ - O.1 ±2 µ - D.1 4 µ - D.1 5 500 µ - D.1 1	V
		I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V	-	-		V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V	-	-		V
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V	-	-	0.55	V
		I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V	-	-	0.55	V
l <sub>l</sub>	input leakage current	$V_I$ = 5.5 V or GND; $V_{CC}$ = 0 V to 5.5 V	-	±0.1	±1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	-	±0.1	±2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A	-	0.1	4	μΑ
Δl <sub>CC</sub>	additional supply current	per pin; V <sub>CC</sub> = 2.3 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	-	5	500	μΑ
Cı	input capacitance	$V_{CC}$ = 3.3 V; $V_I$ = GND to $V_{CC}$	-	5	-	pF

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7 × V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3 × V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_{O}$ = -100 $\mu$ A; $V_{CC}$ = 1.65 V to 5.5 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V	0.95	-	-	V
		$I_{O}$ = -8 mA; $V_{CC}$ = 2.3 V	1.7	-	-	V
		$I_{O}$ = -12 mA; $V_{CC}$ = 2.7 V	1.9	-	-	V
		I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V		-	V	
		$I_{O}$ = -32 mA; $V_{CC}$ = 4.5 V	3.4	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_{O}$ = 100 $\mu$ A; $V_{CC}$ = 1.65 $V$ to 5.5 $V$	-	-	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V	-	-	- V - V 0.35 × V <sub>CC</sub> V 0.7 V 0.8 V 0.3 × V <sub>CC</sub> V  - V - V - V - V - V 0.1 V 0.70 V 0.45 V 0.60 V 0.80 V 0.80 V ±1 µA ±2 µA	V
		I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V	-	-		V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V	-	-	0.60	V
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V	-	-	0.80	V
		I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V	-	-	0.80	V
I	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	±1	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	-	-	±2	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	4	μΑ
ΔI <sub>CC</sub>	additional supply current	per pin; V <sub>CC</sub> = 2.3 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	-	-	500	μΑ

<sup>[1]</sup> All typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

# 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 7.

Symbol	Parameter	Conditions	-40 °C to +85		°C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation	CP to $\overline{Q}$ ; see Fig. 5 [2]						
	delay	V <sub>CC</sub> = 1.65 V to 1.95 V	1.0	3.4	9.9	1.0	13.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.5	2.3	7.0	0.5	9.0	ns
		V <sub>CC</sub> = 2.7 V	0.5	2.5	6.0	0.5	8.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.9	2.4	5.0	0.9	6.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.5	1.8	4.5	0.5	6.0	ns
t <sub>su</sub>	set-up time	HIGH or LOW; D to CP; see Fig. 6 [3]						
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	0.8	-	2.3	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	0.6	-	1.5	-	ns
		V <sub>CC</sub> = 2.7 V	1.5	0.5	-	1.5	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	0.4	-	1.3	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.1	0.5	-	1.1	-	ns
t <sub>h</sub>	hold time	D to CP; see Fig. 6						
		V <sub>CC</sub> = 1.65 V to 1.95 V	0	-0.6	-	0	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0	-0.4	-	0	-	ns
		V <sub>CC</sub> = 2.7 V	+0.5	-0.2	-	0.5	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.9	0.2	-	0.9	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	+0.5	-0.1	-	0.5	-	ns
t <sub>W</sub>	pulse width	CP HIGH or LOW; see Fig. 6						
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	1.1	-	3.0	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.5	0.7	-	2.5	-	ns
		V <sub>CC</sub> = 2.7 V	2.5	0.6	-	2.5	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.5	0.6	-	2.5	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	0.5	-	2.0	-	ns
f <sub>max</sub>	maximum	CP; see Fig. 6						
	frequency	V <sub>CC</sub> = 1.65 V to 1.95 V	160	300	-	160	-	MHz
		V <sub>CC</sub> = 2.3 V to 2.7 V	160	350	-	160	-	MHz
		V <sub>CC</sub> = 2.7 V	160	350	-	160	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	160	350	-	160	-	MHz
		V <sub>CC</sub> = 4.5 V to 5.5 V	200	400	-	200	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_1 = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [4]	-	17	-	-	-	pF

Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;  $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V; N = number of inputs switching;  $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

<sup>[3]</sup> 

 $t_{su}$  is the same as  $t_{su(H)}$  and  $t_{su(L)}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

### 11.1. Waveforms and test circuit

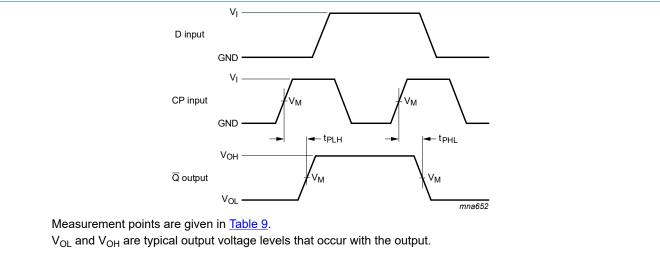
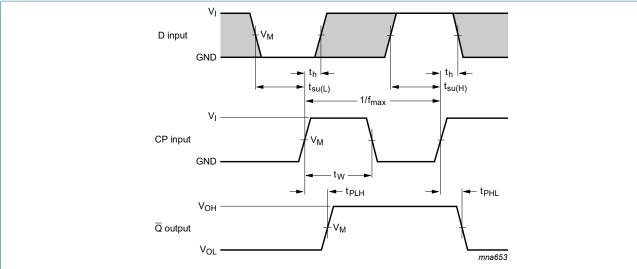


Fig. 5. Clock (CP) to output  $(\overline{\mathbb{Q}})$  propagation delay times



Measurement points are given in Table 9.

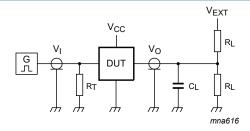
V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output.

The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig. 6. Clock (CP) to output  $(\overline{\mathbb{Q}})$  propagation delay times, clock pulse width, D to set-up times, the CP to D hold times and maximum clock pulse frequency

Table 9. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>
1.65 V to 1.95 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>
2.3 V to 2.7 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>



Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance;

 $C_L$  = Load capacitance including jig and probe capacitance;

R<sub>T</sub> = Termination resistance should be equal to the output impedance Z<sub>o</sub> of the pulse generator;

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

### Fig. 7. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Input Load			V <sub>EXT</sub>	
V <sub>CC</sub>	VI	$t_r = t_f$	CL	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	500 Ω	open

# 12. Package outline

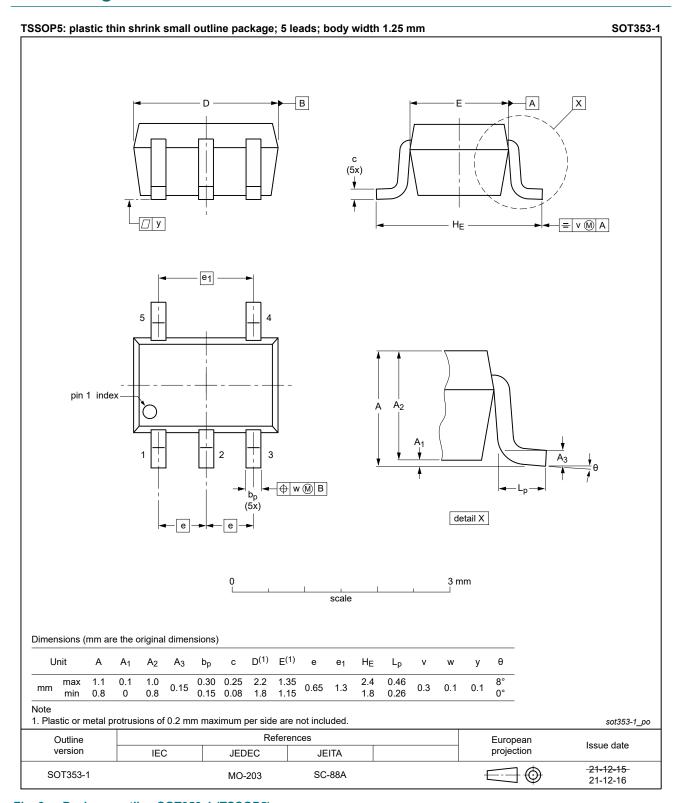


Fig. 8. Package outline SOT353-1 (TSSOP5)

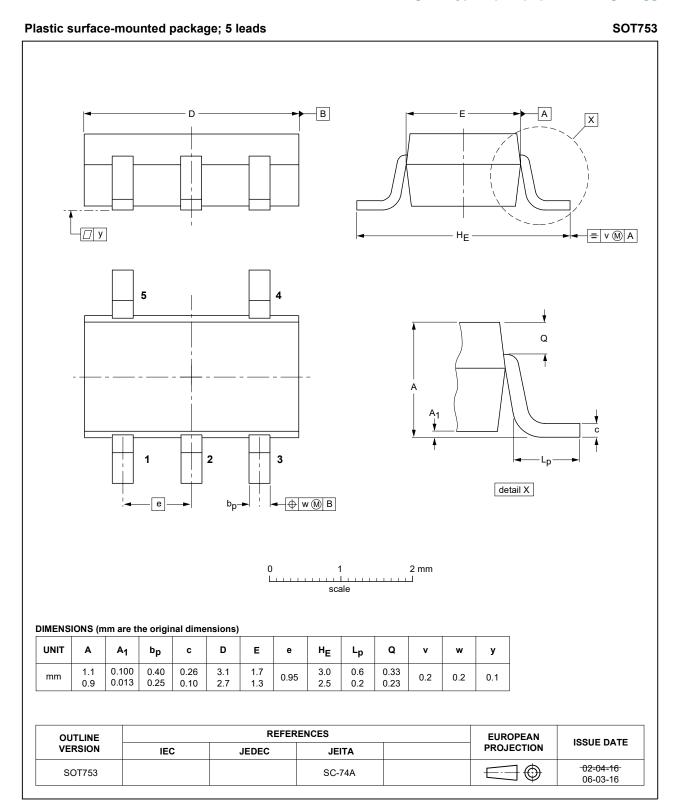


Fig. 9. Package outline SOT753 (SC-74A)

# 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

### Table 12. Revision history

Table 12. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC1G80_Q100 v.3	20220131	Product data sheet	-	74LVC1G80_Q100 v.2		
Modifications:	guidelines c • Legal texts • <u>Section 1</u> ar	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Section 1 and Section 2 updated.</li> <li>Table 5: Derating values for Ptot total power dissipation updated.</li> </ul>				
	• Fig. 8: Pack	• Fig. 8: Package outline drawing SOT353-1 (TSSOP5) has changed.				
74LVC1G80_Q100 v.2	20161212	Product data sheet	-	74LVC1G80_Q100 v.1		
Modifications:	• <u>Table 7</u> : The	<u>Table 7</u> : The maximum limits for leakage current and supply current have changed.				
74LVC1G80_Q100 v.1	20120731	Product data sheet	-	-		

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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### Single D-type flip-flop; positive-edge trigger

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# **Contents**

1. General description	1
2. Features and benefits	1
3. Ordering information	1
4. Marking	2
5. Functional diagram	2
6. Pinning information	2
6.1. Pinning	2
6.2. Pin description	
7. Functional description	
8. Limiting values	
Recommended operating conditions	4
10. Static characteristics	
11. Dynamic characteristics	
11.1. Waveforms and test circuit	
12. Package outline	
13. Abbreviations	
14. Revision history	
15. Legal information	
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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 31 January 2022

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